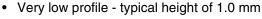
**New Product** 

SS1P3 & SS1P4

Vishay General Semiconductor

## High Current Density Surface Mount Schottky Barrier Rectifiers

# FEATURES • Very low p



- Ideal for automated placement
- Low forward voltage drop, low power losses
- High efficiency
- Low thermal resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

#### TYPICAL APPLICATIONS

For use in low voltage high frequency inverters, freewheeling, dc-to-dc converters, and polarity protection applications.

(Note: These devices are not Q101 qualified.)

#### **MECHANICAL DATA**

Case: DO-220AA (SMP)

Epoxy meets UL 94V-0 flammability rating

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test

Polarity: Color band denotes the cathode end

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	SS1P3	SS1P4	UNIT	
Device marking code		13	14		
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	30	40	V	
Maximum average forward rectified current (Fig. 1)	I <sub>F(AV)</sub>	1.0		А	
Peak forward surge current 10 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	30		А	
Non-repetitive avalanche energy at I <sub>AS</sub> = 1.5 A, L = 10 mH, T <sub>J</sub> = 25 $^\circ\text{C}$	E <sub>AS</sub>	10		mJ	
Voltage rate of change (rated V <sub>R</sub> )	dV/dt	10 000		V/µs	
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	- 55 to + 150		°C	

<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	SS1P3	SS1P4	UNIT
Maximum instantaneous forward voltage <sup>(1)</sup>	I <sub>F</sub> = 1.0 A I <sub>F</sub> = 1.0 A	T <sub>J</sub> = 25 °C T <sub>J</sub> = 125 °C	V <sub>F</sub>	0.50 0.40	0.53 0.45	V
Maximum reverse current at rated $V_R^{(2)}$		T <sub>J</sub> = 25 °C T <sub>J</sub> = 125 °C	I <sub>R</sub>	150 15		μA mA
Typical junction capacitance	4.0 V, 1 MHz		CJ	70		pF

#### Notes:

(1) Pulse test: 300  $\mu$ s pulse width, 1 % duty cycle (2) Pulse test: Pulse width  $\leq$  40 ms



RoHS

COMPLIANT



DO-220AA (SMP)

PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	1 A			
V <sub>RRM</sub>	30 V, 40 V			
I <sub>FSM</sub>	30 A			
E <sub>AS</sub>	10 mJ			
V <sub>F</sub>	0.40 V, 0.45 V			
T <sub>J</sub> max.	150 °C			

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<b>THERMAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	SS1P3	SS1P4	UNIT		
Typical thermal resistance <sup>(1)</sup>	R <sub>θJA</sub> R <sub>θJL</sub> R <sub>θJC</sub>	105 15 25		°C/W		

Note:

(1) Thermal resistance from junction to ambient and junction to lead mounted on P.C.B. with 5.0 x 5.0 mm copper pad areas  $R_{\theta JL}$  is measured at the terminal of cathode band.  $R_{\theta JC}$  is measured at the top centre of the body

ORDERING INFORMATION (Example)					
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
SS1P3-E3/84A	0.024	84A	3000	7" diameter plastic tape and reel	
SS1P3-E3/85A	0.024	85A	10 000	13" diameter plastic tape and reel	

#### **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

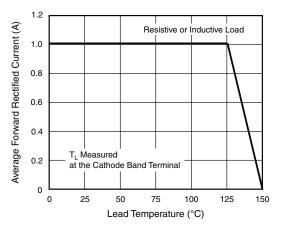


Figure 1. Maximum Forward Current Derating Curve

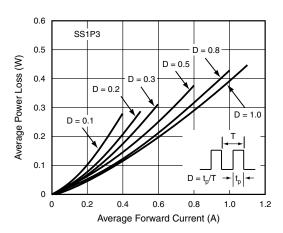


Figure 2. Forward Power Loss Characteristics

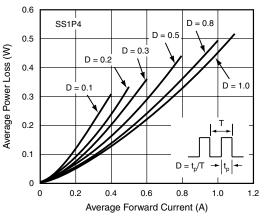


Figure 3. Forward Power Loss Characteristics

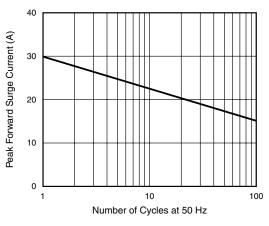


Figure 4. Typical Instantaneous Forward Characteristics



# SS1P3 & SS1P4

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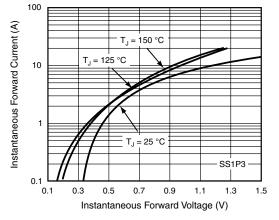


Figure 5. Typical Instantaneous Forward Characteristics

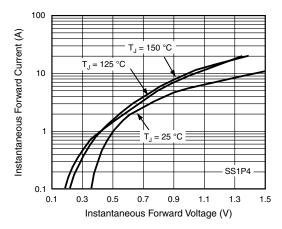


Figure 6. Typical Instantaneous Forward Characteristics

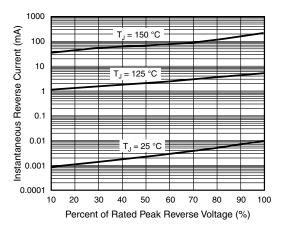


Figure 7. Typical Reverse Leakage Characteristics

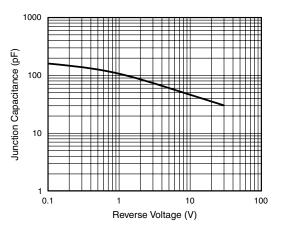


Figure 8. Typical Junction Capacitance

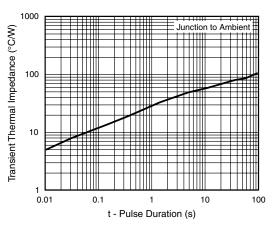


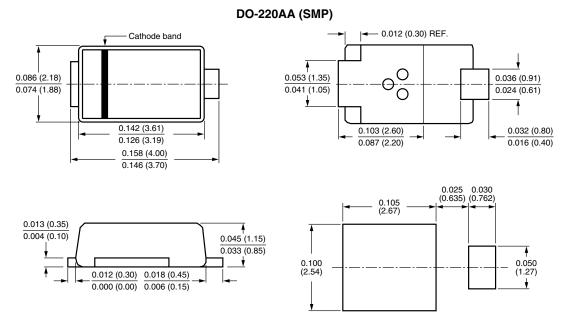
Figure 9. Typical Transient Thermal Impedatnce





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### PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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